

YJ Planar Schottky Barrier Diode Die Specification

45V 25A, 130mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB130M045SS-290A

Main Products Characteristics

- Average forward current: $I_F(AV) = 25\text{ A}$
- Maximum operating junction temperature: $T_j = 150\text{ }^{\circ}\text{C}$